PRELIMINARY DATA SHEET

NEC

BIPOLAR ANALOG INTEGRATED CIRCUIT

μPC8187TB

SILICON MMIC HI-IP3 FREQUENCY UP-CONVERTER FOR WIRELESS TRANSCEIVER

DESCRIPTION

The μPC8187TB is a silicon monolithic integrated circuit designed as frequency up-converter for wireless transceiver. This IC is higher operating frequency, lower distortion and higher conversion gain than conventional μPC8163TB.

This IC is manufactured using NEC's 30 GHz f_{max} UHS0 (Ultra High Speed Process) silicon bipolar process.

FEATURES

- High output frequency : f_{RFout} = 0.8 to 2.5 GHz
- High-density surface mounting : 6-pin super minimold package
- Supply voltage : V_{CC} = 2.7 to 3.3 V

APPLICATION

- TDMA, PCS, CDMA etc.

ORDERING INFORMATION

Part Number	Package	Marking	Supplying Form
μPC8187TB-E3	6-pin super minimold	C3G	• Embossed tape 8 mm wide. • Pin 1, 2, 3 face the tape perforation side. • Qty 3 kpcs/reel.

Remark To order evaluation samples, please contact your local NEC sales office.
(Part number for sample order: μPC8187TB)

Caution Electro-static sensitive devices

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

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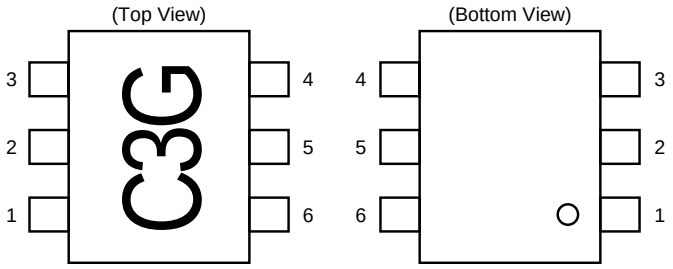
PIN CONNECTIONS



Pin No.	Pin Name
1	IFinput
2	GND
3	LOinput
4	GND
5	V_{CC}
6	RFoutput

SERIES PRODUCTS (T_A = +25°C, V_{CC} = V_{PS} = V_{RFout} = 3.0 V, Z_S = Z_L = 50 Ω)

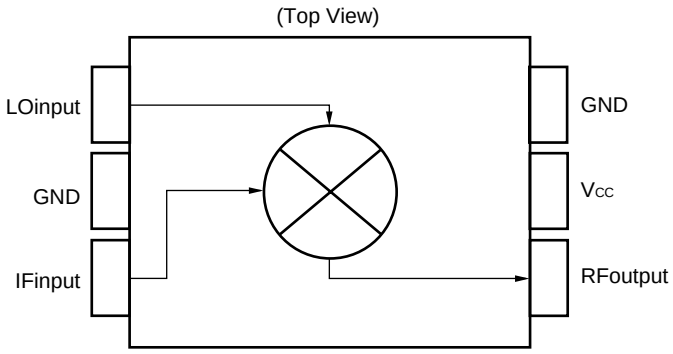
Part Number	I_{CC} (mA)	f_{RFout} (GHz)	CG (dB)		
			@RF 0.9 GHz[Note]	@RF 1.9 GHz	@RF 2.4 GHz
μPC8187TB	15	0.8 to 2.5	11	11	10
μPC8106TB	9	0.4 to 2.0	9	7	–
μPC8172TB	9	0.8 to 2.5	9.5	8.5	8.0
μPC8109TB	5	0.4 to.2.0	6	4	–
μPC8163TB	16.5	0.8 to 2.0	9	5.5	–

Part Number	$P_{O(sat)}$ (dBm)			OIP_3 (dBm)		
	@RF 0.9 GHz[Note]	@RF 1.9 GHz	@RF 2.4 GHz	@RF 0.9 GHz[Note]	@RF 1.9 GHz	@RF 2.4 GHz
μPC8187TB	+4	+2.5	+1	+10	+10	+8.5
μPC8106TB	–2	–4	–	+5.5	+2.0	–
μPC8172TB	+0.5	0	–0.5	+7.5	+6.0	+4.0
μPC8109TB	–5.5	–7.5	–	+1.5	–1.0	–
μPC8163TB	+0.5	–2	–	+9.5	+6.0	–

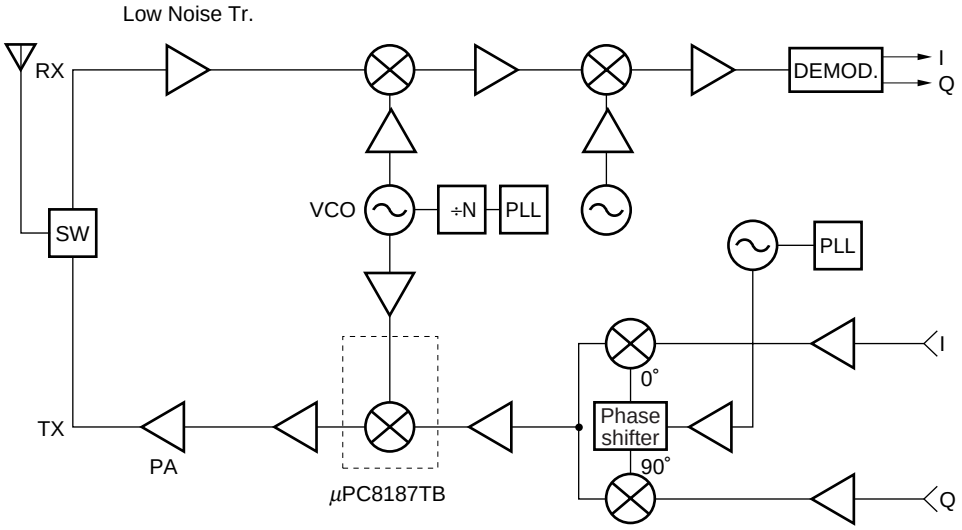
Note f_{RFout} = 0.83 GHz @ μPC8163TB and μPC8187TB

Remark Typical performance. Please refer to **ELECTRICAL CHARACTERISTICS** in detail.
To know the associated product, please refer to each latest data sheet.

BLOCK DIAGRAM (FOR THE μPC8187TB)

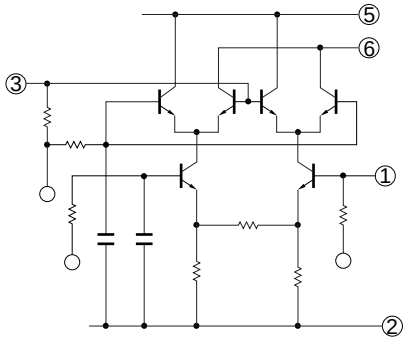


SYSTEM APPLICATION EXAMPLES (SCHEMATICS OF IC LOCATION IN THE SYSTEM)



To know the associated products, please refer to each latest data sheet.

PIN EXPLANATION

Pin No.	Pin Name	Applied Voltage (V)	Pin Voltage (V)[Note]	Function and Explanation	Equivalent Circuit
1	IFinput	–	1.2	This pin is IF input to double balanced mixer (DBM). The input is designed as high impedance. The circuit contributes to suppress spurious signal. Also this symmetrical circuit can keep specified performance insensitive to process-condition distribution. For above reason, double balanced mixer is adopted.	
2 4	GND	GND	–	GND pin. Ground pattern on the board should be formed as wide as possible. Track Length should be kept as short as possible to minimize ground impedance.	
3	LOinput	–	2.1	Local input pin. Recommendable input level is –10 to 0 dBm.	
5	V_{CC}	2.7 to 3.3	–	Supply voltage pin.	
6	RFoutput	Same bias as V_{CC} through external inductor	–	This pin is RF output from DBM. This pin is designed as open collector. Due to the high impedance output, this pin should be externally equipped with LC matching circuit to next stage.	

Note Each pin voltage is measured at $V_{CC} = V_{PS} = V_{RFout} = 2.8$ V.

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Rating	Unit
Supply Voltage	V_{CC}	T_A = +25°C	3.6	V
Power Dissipation of Package	P_D	Mounted on double-side copperclad 50 × 50 × 1.6 mm epoxy glass PWB (T_A = +85°C)	270	mW
Operating Ambient Temperature	T_A		–40 to +85	°C
Storage Temperature	T_{stg}		–55 to +150	°C
Maximum Input Power	P_{in}		+10	dBm

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit	Remarks
Supply Voltage	V_{CC}	2.7	2.8	3.3	V	The same voltage should be applied to pin 5 and 6
Operating Ambient Temperature	T_A	–40	+25	+85	°C	
Local Input Level	P_{LOin}	–10	–5	0	dBm	Z_S = 50 Ω (without matching)
RF Output Frequency	f_{RFout}	0.8	–	2.5	GHz	With external matching circuit
IF Input Frequency	f_{IFin}	50	–	400	MHz	

ELECTRICAL CHARACTERISTICS

(T_A = +25°C, V_{CC} = V_{RFout} = 2.8 V, f_{IFin} = 150 MHz, P_{LOin} = –5 dBm)

Parameter	Symbol	Test Conditions[Note]	MIN.	TYP.	MAX.	Unit
Circuit Current	I_{CC}	No signal	11	15	19	mA
Conversion Gain	CG1	f_{RFout} = 0.83 GHz, P_{IFin} = –20 dBm	8	11	14	dB
	CG2	f_{RFout} = 1.9 GHz, P_{IFin} = –20 dBm	8	11	14	dB
	CG3	f_{RFout} = 2.4 GHz, P_{IFin} = –20 dBm	7	10	13	dB
Saturated RF Output Power	$P_{O(sat)}1$	f_{RFout} = 0.83 GHz, P_{IFin} = 0 dBm	+1.5	+4	–	dBm
	$P_{O(sat)}2$	f_{RFout} = 1.9 GHz, P_{IFin} = 0 dBm	0	+2.5	–	dBm
	$P_{O(sat)}3$	f_{RFout} = 2.4 GHz, P_{IFin} = 0 dBm	–1.5	+1	–	dBm

Note $f_{RFout} < f_{LOin}$ @ f_{RFout} = 0.83 GHz

$f_{LOin} < f_{RFout}$ @ f_{RFout} = 1.9 GHz/2.4 GHz

OTHER CHARACTERISTICS, FOR REFERENCE PURPOSES ONLY

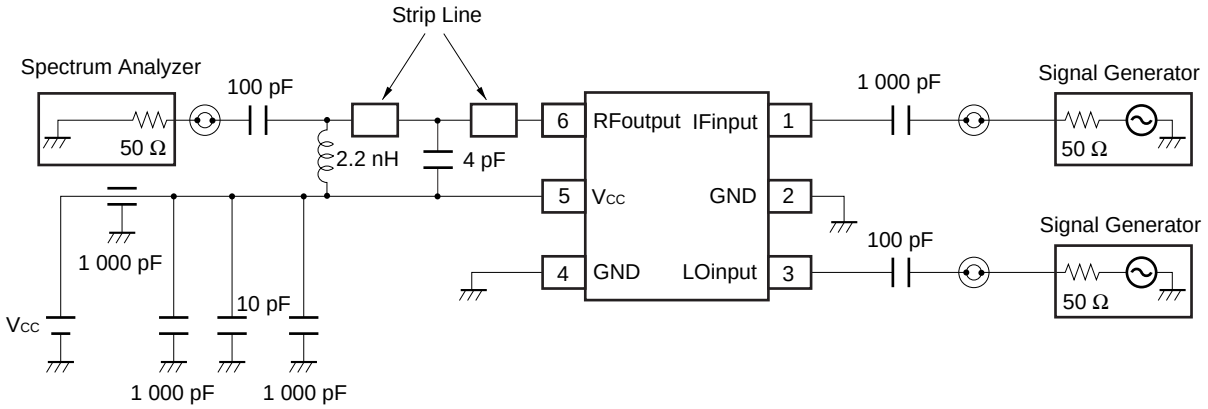
(T_A = +25°C, V_{CC} = V_{RFout} = 2.8 V, P_{LOin} = –5 dBm)

Parameter	Symbol	Test Conditions[Note]		Value	Unit
Output Third-Order Distortion Intercept Point	$OIP_3$1	f_{RFout} = 0.83 GHz	f_{IFin}1 = 150 MHz f_{IFin}2 = 151 MHz	+10	dBm
	$OIP_3$2	f_{RFout} = 1.9 GHz		+10	dBm
	$OIP_3$3	f_{RFout} = 2.4 GHz		+8.5	dBm
Input Third-Order Distortion Intercept Point	$IIP_3$1	f_{RFout} = 0.83 GHz	f_{IFin}1 = 150 MHz f_{IFin}2 = 151 MHz	–1.0	dBm
	$IIP_3$2	f_{RFout} = 1.9 GHz		–1.0	dBm
	$IIP_3$3	f_{RFout} = 2.4 GHz		–1.5	dBm
SSB Noise Figure	SSB•NF1	f_{RFout} = 0.83 GHz	f_{IFin} = 150 MHz	11	dB
	SSB•NF2	f_{RFout} = 1.9 GHz		12	dB
	SSB•NF3	f_{RFout} = 2.4 GHz		12.5	dB

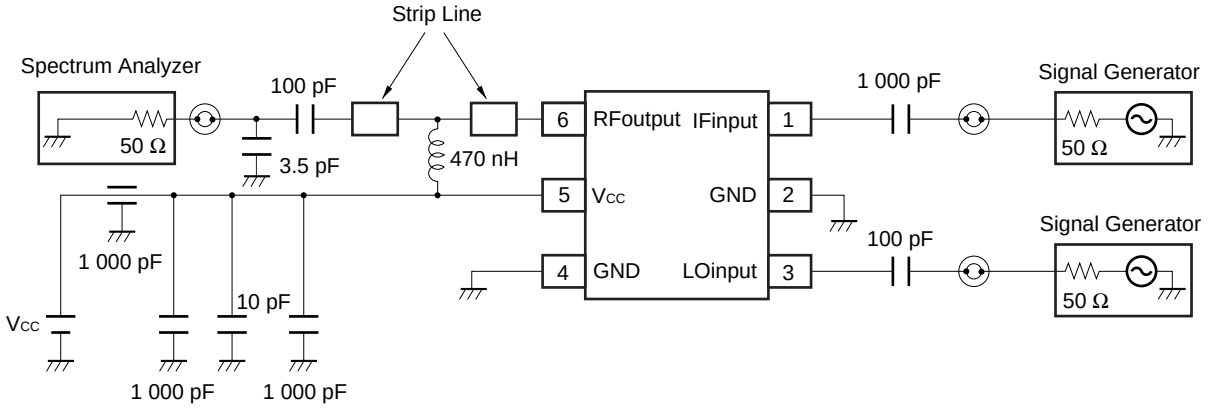
Note $f_{RFout} < f_{LOin}$ @ f_{RFout} = 0.83 GHz

$f_{LOin} < f_{RFout}$ @ f_{RFout} = 1.9 GHz/2.4 GHz

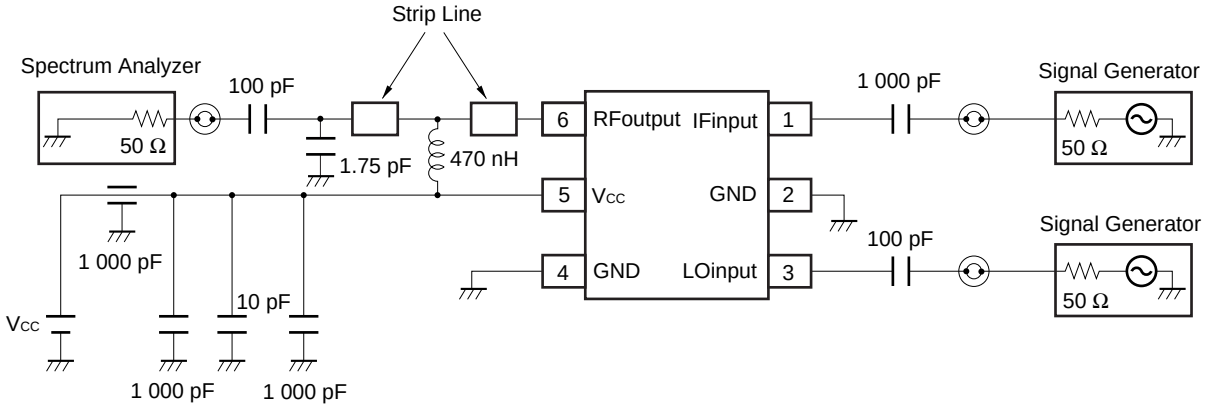
TEST CIRCUIT 1 (f_{RFout} = 0.83 GHz)



TEST CIRCUIT 2 (f_{RFout} = 1.9 GHz)

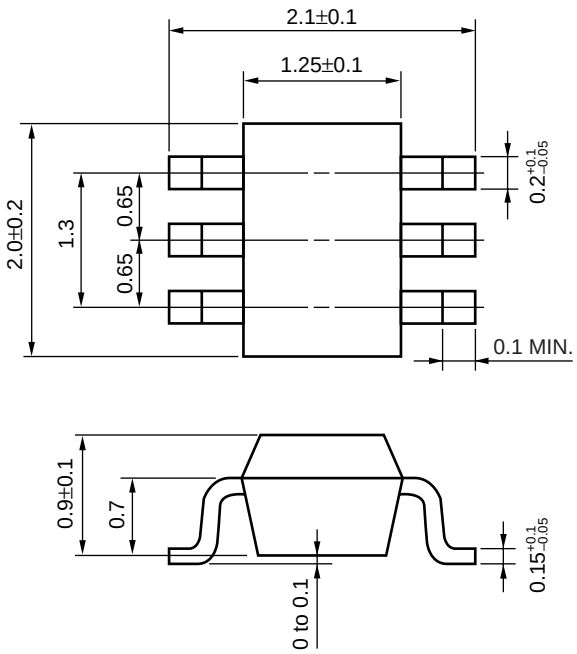


TEST CIRCUIT 3 (f_{RFout} = 2.4 GHz)



PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



NOTE ON CORRECT USE

(1) Observe precautions for handling because of electrostatic sensitive devices.
(2) Form a ground pattern as wide as possible to minimize ground impedance (to prevent undesired oscillation).
(3) Connect a bypass capacitor to the V_{CC} pin.
(4) Connect a matching circuit to the RF output pin.
(5) The DC cut capacitor must be each attached to the input and output pins.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared Reflow	Package peak temperature: 235°C or below Time: 30 seconds or less (at 210°C) Count: 3, Exposure limit: None[Note]	IR35-00-3
VPS	Package peak temperature: 215°C or below Time: 40 seconds or less (at 200°C) Count: 3, Exposure limit: None[Note]	VP15-00-3
Wave Soldering	Soldering bath temperature: 260°C or below Time: 10 seconds or less Count: 1, Exposure limit: None[Note]	WS60-00-1
Partial Heating	Pin temperature: 300°C Time: 3 seconds or less (per side of device) Exposure limit: None[Note]	–

Note After opening the dry pack, keep it in a place below 25°C and 65% RH for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

[MEMO]

[MEMO]

ATTENTION

OBSERVE PRECAUTIONS
FOR HANDLING
ELECTROSTATIC
SENSITIVE
DEVICES

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